

Optical switching of carrier transport in transistors based on an organic bicomponent blend

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Novel multifunctional devices can be fabricated by combining organic semiconductors with molecules possessing different chemical, optical and electrical properties. Diarylethene molecules (DAEs) have attracted a great deal of attention thanks to their efficient interconversion between two thermodynamically stable isomers that exhibit remarkably different electronic properties, allowing to introduce controlled photo-modulable trap levels in the semiconductor bulk.^[1] We have achieved bi-functionality exploiting DAEs in combination with PDVT-8 or PCDTPT polymers as a bi-component active layer in organic thin-film transistors (OTFTs). These polymers have been chosen as p-type semiconductors because they feature high field effect mobility (up to $1 \text{ cm}^2\text{V}^{-1}\text{s}^{-1}$) and HOMO energy levels that allow electronic interaction with the closed form of DAE-Me.^[2,3] These findings are of interest for the development of high-performing optically gated electronic devices, such as switches and multilevel non-volatile optical memories,^[4] therefore for a new generation of electronics. Finally, we explore the possibility of introducing a third functional component to control the modulation of the surface charge density at the semiconductor/dielectric interface.

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References:

- [1] Orgiu, E.; Crivillers, N.; Herder, M.; Grubert, L.; Pätzelt, M.; Frisch, J.; Pavlica, E.; Duong, D.T.; Bratina, G.; Salleo, A.; Koch, N.; Hecht, S.; Samorì, P., *Nature Chemistry*, **2012** 4, 675–679.
- [2] Chen, H.; Guo, Y.; Yu, G.; Zhao, Y.; Zhang, J.; Gao, D.; Liu, H.; Liu, Y., *Advanced materials*, **2012**, 24, 4618–22.
- [3] Ying, L.; Hsu, B.B.Y.; Zhan, H.; Welch, G.C.; Zalar, P.; Perez, L.A.; Kramer, E.J.; Nguyen, T.; Heeger, A.J.; Wong, W.; Bazan, G.C., *Journal of the American Chemical Society*, **2011**, 133, 18538–18541.
- [4] Leydecker, T.; Herder, M.; Pavlica, E.; Bratina, G.; Hecht, S.; Orgiu, E.; Samorì, P., *Nature Nanotechnology*, **2016**, 11, 769–775.